NEW CAD MODEL OF THE MICROSTRIP INTERDIGITAL CAPACITOR

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A new model for the microstrip line interdigital capacitor is proposed. This model consists of calculating the $2N \times 2N$ $Y$-matrix of the $N$ coupled lines using the multiple coupled line tool. Then, this matrix is reduced to a $2 \times 2$ matrix using simple circuit theory. The capacitance at the end of each finger is taken into consideration using closed-form expression of the coplanar waveguide open-end capacitance. This model can predict the resonances that might appear around the quarter-wavelength frequency. These resonances are caused by the coupling between the fingers and exist only in capacitors with four fingers or more. Very good agreement is obtained between the results of our model and those obtained using the software HFSS and measurements.

Keywords: Capacitors; Interdigital capacitors; Microstrip capacitors; Multiple coupled lines

1 INTRODUCTION

Interdigital capacitors (ICAPs) are frequently used in microstrip (MS) microwave integrated circuits. The properties of this type of capacitor have been studied by many authors [1–15]. Coupled line theory was used in Refs. [1, 3–5] to derive the impedance matrix of these capacitors. Many assumptions were made, some of which are: (1) only coupling between adjacent fingers is considered; (2) the number of fingers is large such that a periodic smooth structure can be assumed; (3) capacitor dimensions are much less than a quarter wavelength; and (4) capacitance at the end of each finger is neglected. An improved model in which the capacitor is divided into its basic subcomponents was very briefly described in Ref. [6]. These subcomponents included bends, T-junctions, gaps, open-ends, and uniform transmission lines. Existing computer models were used to characterize these subcomponents. Full-wave analysis and/or measurements were used in Refs. [8, 12, 14, 15] to study the MS ICAP. A measurement-based lumped-element model was given in Ref. [7]. Conformal mapping was used in Refs. [9, 11, 13] to derive simple closed-form expressions for the capacitance of multilayered ICAPs.

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In this article, a new model for the MS ICAP is proposed and tested. In this model, all the coupling effects between the fingers are taken into account using the fast multiple coupled line (MCPL) tool in the CAD software Serenade [16]. In this tool, the $2N \times 2N$ admittance matrix of the $N$-fingers' section is obtained using the Spectral Domain technique, which is then reduced to $2 \times 2$ matrix using simple circuit theory. The capacitance at the end of each finger is taken into consideration using closed-form expression of the coplanar waveguide (CPW) open-end capacitance [17]. It is shown that this model can predict the resonances that might appear due to coupling when long fingers are considered. To our knowledge, these resonances occurring in ICAPs have not been reported in the literature before.

The model is briefly described in Section 2, while validation and numerical results are presented in Section 3.

2 CAPACITOR MODEL

Figure 1 shows the MS ICAP under investigation. The ICAP itself consists of $N$ fingers, each of width $W$, with an overlapping distance $L_p$. The number of fingers $N$ could be even or odd. An odd $N$ would give different phases for $S_{11}$ and $S_{22}$, which cannot be predicted by the coupled-line theory models mentioned above. The separation distance $S$ between adjacent fingers is assumed to be constant. Similarly, the widths of all fingers are assumed to be equal (denoted by $W$). At the end of each finger, there is a gap with width $G$ that gives rise to an end-capacitance between each finger and the terminal strips. The terminal strips have equal lengths of $W_T$, and are fed with MS lines of widths $W_{f1}$ and $W_{f2}$.

Our approach in modeling the MS ICAP can be summarized in the following steps.

1. First, the MCPL tool [16], which takes into account all the coupling effects between the fingers, is used to derive the $2N \times 2N$ $Y$-matrix of the ICAP fingers. It should be mentioned that one main advantage of using the MCPL tool, although not investigated here, is the ability to analyze an ICAP with different strip widths and/or different spacings between the fingers.

2. The second step is to reduce this $2N \times 2N$ $Y$-matrix to a $2 \times 2$ matrix. After extensive experiments, it has been found that the ICAP structure can be effectively modeled as shown in Figure 2. The capacitors model the gap capacitances that exist at the end of each finger. This capacitance can be approximately modeled as a CPW open-end capacitance [11, 13]. The formula for the CPW open-end capacitance given in Ref. [17] is used to compute this capacitance. This formula, which was derived analytically in Ref. [17] under narrow-slot assumption, has been found to give very good results for the end-capacitance.

![Figure 1](image-url)
Alternatively, for wide gaps, the simple asymptotic value for the end-capacitance given in Ref. [18] can be used. In Figure 2, the transmission line (TRL) sections, connected directly to the MCPL nodes, are used to model those small MS sections at the beginning of each finger. These strip sections are of length $G$ and width $W$. This model has proven to give very good results compared to full-wave results obtained using the HFSS software [16], as will be shown below.

3. To simplify the problem of reducing the $2N \times 2N$ $Y$-matrix to a $2 \times 2$ matrix, the small TRL sections were replaced by inductors. The inductance for each section is simply given by [19]:

$$Z_L = j\omega L = jZ_0\beta \ell,$$

(1)

where $\ell$ is equal to the gap width $G$, $Z_0$ is the characteristic impedance of an MS line of width $W$, and $\beta$ is the phase constant. This replacement of the TRL sections by inductors is facilitated by the fact that their lengths are very small compared to the wavelength, and the fact that they have high impedance (since the finger width is small). The effect of these inductors on the response of the ICAP has been found to be very small. However, their effect becomes noticeable at high frequencies.

4. Figure 3 shows the final model of the ICAP itself. What is needed is the $2 \times 2$ $Y$-matrix that relates the input and output currents and voltages ($I_1, I_2, V_1$, and $V_2$), given the $2N \times 2N$ $Y$-matrix of the MCPL section that relates the currents and voltages at the finger terminals ($I_1, \ldots, I_{2N}, V_1, \ldots, V_{2N}$). The main steps in this derivation are presented below.

From Figure 3, the following set of equations can be written:

$$I_1 = \frac{V_1' - V_1}{Z_L} = Y_{1,1}V_1 + Y_{1,2}V_2 + \cdots + Y_{1,2N}V_{2N},$$

(2)

$$I_2 = (V_2' - V_2)Y_c = Y_{2,1}V_1 + Y_{2,2}V_2 + \cdots + Y_{2,2N}V_{2N},$$

(3)

$$I_3 = \frac{V_3' - V_3}{Z_L} = Y_{3,1}V_1 + Y_{3,2}V_2 + \cdots + Y_{3,2N}V_{2N},$$

(4)
where $Y_c = j\omega C$. Similar equations can be written for the rest of the MCPL nodes. The above
2N equations can be written in matrix form as:

$$[A][V] = [B][V'],$$

where $[A]$ is a $2N \times 2N$ matrix whose elements are related to the elements of the MCPL
$Y$-matrix, $[V]$ is a $2N \times 1$ vector that contains the voltages at the MCPL nodes, $[B]$ is a
$2N \times 2$ matrix, and $[V']$ is a $2 \times 1$ vector. From the above equation, one can get all the voltages at the MCPL
nodes as functions of $V'_1$ and $V'_2$ by inverting the matrix $[A]$ numerically and multiplying it by the matrix $[B]$.

Then, using the fact that

$$I'_1 = I_1 + I_2 + \cdots + I_N$$
$$I'_2 = I_{N+1} + I_{N+2} + \cdots + I_{2N}$$

one can write the following matrix equalities:

$$[I'] = [D][I] = [D][Y][V] = [D][Y][A]^{-1}[B][V'] = [Y'][V'],$$

where $[D]$ is a $2 \times 2N$ matrix obtained from Eqs. (6) and (7), and $[Y']$ is the needed $2 \times 2$
matrix.

5. It should be emphasized that the above $2 \times 2 Y$-matrix models the ICAP itself, i.e., the
fingers and the gaps at the end of the fingers. Finally, the rest of the ICAP structure could
be taken into account, as explained in Ref. [6], using TRL sections, steps, bends, and T-junction elements.

3 RESULTS

Extensive numerical experiments have been carried out using the above model. A sample of
the obtained results is presented here.

1. The first example has $N = 9$, $W = 0.4$ mm, $S = G = 0.2$ mm, $L_p = 1.4$ mm, $W_T = 0.4$ mm,
$W_{F1} = W_{F2} = 1.2$ mm, substrate thickness $h = 1.27$ mm, and dielectric constant $\varepsilon_r = 10.2$.
The feeding lines have a $50 \Omega$ characteristic impedance. Figures 4 and 5 show the obtained
scattering parameters as compared to those obtained using the full-wave finite element
FIGURE 4 Magnitude of scattering parameters of an MS ICAP. \( N = 9 \), \( W = 0.4 \) mm, \( S = G = 0.2 \) mm, \( L_p = 1.4 \) mm, \( W_T = 0.4 \) mm, \( W_{P1} = W_{P2} = 1.2 \) mm, substrate thickness \( h = 1.27 \) mm, and dielectric constant \( \varepsilon_r = 10.2 \).

FIGURE 5 Phase of scattering parameters of an MS ICAP. Refer to Figure 4 for dimensions.

FIGURE 6 Magnitude of scattering parameters of an MS ICAP. \( N = 5 \), \( W = 25 \) \( \mu \)m, \( S = G = 20 \) \( \mu \)m, \( L_p = 300 \) \( \mu \)m, \( W_T = 50 \) \( \mu \)m, \( W_{P1} = W_{P2} = 100 \) \( \mu \)m, \( h = 50 \) \( \mu \)m, and \( \varepsilon_r = 12.9 \).
software HFSS [16]. It can be seen that good agreement is obtained, with a maximum difference of 4% for $S_{11}$, and 9% for $S_{21}$ at 6 GHz. This difference could be due to the parasitic effects inherent in the ICAP structure, which are neglected in the MCPL model. For example, in the MCPL model, the coupling between the terminal strips, and their coupling

![Figure 7: Phase of scattering parameters of an MS ICAP. Refer to Figure 6 for dimensions.](image)

![Figure 8: Magnitude of scattering parameters of a 4-fingers MS ICAP.](image)
to the fingers of the ICAP are neglected. Moreover, the parasitic effects of the several bends and T-junctions, existing in the ICAP structure, and radiation loss are neglected in the MCPL model. A very fine mesh had to be considered in the HFSS simulation to reach convergence. On the other hand, it took only a few seconds to obtain the results using the MCPL model in the whole frequency range (with 0.01 GHz frequency increment). An ICAP with the same dimensions was analyzed and measured in Ref. [14] and the theoretical results are shown in Figure 4. A full-wave method of moments was used for the analysis in Ref. [14]. The cause of the difference between our results (both MCPL model and HFSS) and those from Ref. [14] is not clear. The phase of the scattering parameters was not shown in Ref. [14]. It can be seen from Figure 5 that the phase of $S_{11}$ is slightly different from the phase of $S_{22}$ since an odd number of fingers is considered.

2. The second example has $N = 5$, $W = 25$ μm, $S = G = 20$ μm, $L_p = 300$ μm, $W_T = 50$ μm, $W_{F1} = W_{F2} = 100$ μm, $h = 50$ μm, and $\varepsilon_r = 12.9$. It should be noted that the characteristic impedance of the feeding lines is around 30Ω, which is used as reference for the S-parameter calculations. Figures 6 and 7 show the results. The agreement between the MCPL model and HFSS results is very good in the whole frequency range from 10 to 50 GHz. It should be noted that although an open structure is considered in the HFSS simulation, the agreement with the MCPL model results is very good, which indicates that the radiation loss from this ICAP is very small.

3. As a third example, an MS ICAP with the following dimensions has been analyzed: $N = 4$, $W = 0.316$ mm, $S = 0.3$ mm, $G = 0.341$ mm, $L_p = 13.7$ mm, $W_T = 0.5$ mm,

![Figure 9](image-url)  
**FIGURE 9** Magnitude of scattering parameters for a 5-fingers MS ICAP. $W = 0.15$ mm, $S = 0.125$ mm, $G = 0.125$ mm, $L_p = 6.9$ mm, $W_T = 0.3$ mm, $W_{F1} = W_{F2} = 0.56$ mm, $h = 0.635$ mm, and $\varepsilon_r = 10.2$. 


$W_{F1} = W_{F2} = 1.868 \text{ mm}, \ h = 0.787 \text{ mm}, \ \text{and} \ \varepsilon_r = 3.2$. Figure 8 shows the results obtained using the MCPL model as compared to HFSS simulations. It is very interesting to notice the resonances appearing between 3 and 4 GHz. In practice, an ICAP is usually used at frequencies well below the first quarter-wavelength frequency, i.e., in the region where it behaves as a capacitor with negligible parasitics.

It was found that a 3-fingers MS ICAP with the same dimensions did not show these resonances, while they continue to appear for $N$ larger than 4 fingers. Moreover, the number of these resonances was related to the number of fingers, as shown in the next example. After extensive simulations, it was concluded that these resonances are due to the coupling between the fingers. They occur around the frequencies at which the length of the ICAP is an odd multiple of quarter wavelength. These resonances are similar to those occurring in coupled lines bandpass filters. To our knowledge, such resonances occurring in interdigital capacitors have not been shown before in the literature.

4. Figure 9 shows the scattering parameters for an MS ICAP with the following dimensions: $N = 5$, $W = 0.15 \text{ mm}$, $S = 0.125 \text{ mm}$, $G = 0.125 \text{ mm}$, $L_p = 6.9 \text{ mm}$, $W_T = 0.3 \text{ mm}$, $W_{F1} = W_{F2} = 0.56 \text{ mm}$, $h = 0.635 \text{ mm}$, and $\varepsilon_r = 10.2$. It can be noticed that a single resonance appears around 4.5 GHz in both the MCPL model and HFSS simulations. Again, the agreement is very good, which validates the proposed MCPL model.

5. As a last example, Figure 10 shows the scattering parameters for an MS ICAP with the following dimensions: $N = 4$, $W = 0.5 \text{ mm}$, $S = 0.5 \text{ mm}$, $G = 0.5 \text{ mm}$, $L_p = 14 \text{ mm}$,

![Figure 10](image_url)  

**FIGURE 10** Magnitude of scattering parameters for a 4-fingers MS ICAP. $N = 4$, $W = 0.5 \text{ mm}$, $S = 0.5 \text{ mm}$, $G = 0.5 \text{ mm}$, $L_p = 14 \text{ mm}$, $W_T = 1 \text{ mm}$, $W_{F1} = W_{F2} = 2.1 \text{ mm}$, $h = 0.508 \text{ mm}$, and $\varepsilon_r = 3.38$. 
$W_T = 1 \text{ mm}$, $W_{F1} = W_{F2} = 2.1 \text{ mm}$, $h = 0.508 \text{ mm}$, and $\varepsilon_r = 3.38$. Experimental results are also shown in the figure. The circuit was fabricated on Rogers 4003C substrate (with 34 $\mu$m copper thickness) using the LPKF ProtoMat 91s/VS mill/drill unit, which is usually used to produce prototype PCBs. Measurements were performed using an HP 8510 Network Analyzer, along with TRL calibration. It can be seen that both the MCPL model and experiments predict the resonances at the same frequencies. The differences can be attributed to the finite size ground plane used in the measurements, calibration errors, connectors’ effects, and the other parasitic effects mentioned above in the first example.

4 CONCLUSIONS

A new model for the MS ICAP has been developed. This model is based on the use of the MCPL programs to obtain the $\Lambda$ matrix of the $N$ coupled fingers. Then, it is reduced to a $2 \times 2$ admittance matrix using simple network theory. This new model has been verified by comparison to full-wave results obtained using HFSS. It has been shown that a band-pass filterlike effect can exist in interdigital capacitors with four fingers or more. This effect has been validated by HFSS simulations and experiments.

References

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